PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Daisuke NAGAO et al.

Application No.: New US Application

Filed: February 3, 2004 Docket No.: 118543

For: MANUFACTURING METHOD FOR THREE-DIMENSIONAL STRUCTURAL BODY

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of the non-English language references is discussed in the present specification.
- 3. English-language Abstracts of the non-English language references Nos. 1-2 are attached hereto.
- 4. A computer-generated English translation of the following Japanese Patent Publication has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See References 1-2.

Respectfully submitted,

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JAO:JSA/tmw

Date: February 3, 2004

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INFORMATION DISCLOSURE STATEMENT											
(Use several sheets if necessary)			APPLICANTS Daisuke NAGAO et al.								
				FILING DATE February 3, 2004							
U.S. PATENT DOCUMENTS											
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		DOCUMENT NUMBER	DATE		COUNTRY			CLASS	SUB CLASS		
	1	JP A 2001-160654 (with abstract and translation)	06/12/2001		Japan						
	2	JP B2 3161362 (with abstract and translation)	02/	23/2001	Japan .		·				
	· · · · ·	OTHER DOCUMENTS (In	cludii	ng Author,	Title, Date, Pertinent Page	es, etc.)					
	3	Aoki et al, "Three-dimensional photonic crystals for optical wavelengths assembled by micromanipulation", Applied Physics Letters, Volume 81, Number 17, October 21, 2002, pp 3122-3124									
	4	Yablonovitch, "Inhibited Spontaneous Emission in Solid-State Physics and Electronics", Physical Review Letters, Volume 58, Number 20, May 18, 2987, pp 2059-2062									
	5	Kosaka et al, "Anisotropic Dispersion in Photonic Crystals - Super-Prism Phenomena", 17p-T-13 (1998)									
	6	Joannopoulos et al, "Photonic Crystal", Princeton University Press, 1995, p100-104									
	7	Baba et al, "Photonic crystals and their applications", Yokohama National University, 1998, pp 1041-1045									
	8	Kawakami, "Photonic Crysteal Technique and Its Application, CMC Publication, Chapter 11, 2002, pp 157-169									
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		citation considered, whether or not cance and not considered. Include copy					line th	rough citati	on if not in		

Date: February 3, 2004